MA3J745 (MA745)

Silicon epitaxial planar type

For switching

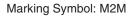
Features

- \bullet Forward voltage $V_{\rm F}$, optimum for low voltage rectification
- Low V_F type of MA3X704A (MA704A)
- Optimum for high frequency rectification because of its short reverse recovery time t_{rr}

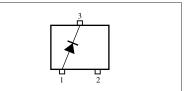
Unit: mm
$-++ 0.3^{+0.1}_{-0.05}$
13
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$
1 : Anode 5 9
3 : Cathode
EIAJ: SC-79 SMini3-F1 Package

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Reverse voltage	V _R	30	V
Maximum peak reverse voltage	V _{RM}	30	V
Forward current	I_F	30	mA
Peak forward current	I _{FM}	150	mA
Junction temperature	Tj	125	°C
Storage temperature	T _{stg}	-55 to +125	°C



Internal Connection



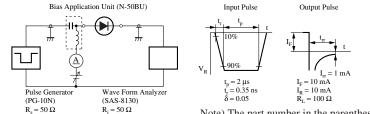
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	V _{F1}	$I_F = 1 \text{ mA}$			0.3	V
	V _{F2}	$I_F = 30 \text{ mA}$			1.0	
Reverse current	I _R	$V_{R} = 30 V$			30	μΑ
Terminal capacitance	Ct	$V_R = 1 V, f = 1 MHz$		1.5		pF
Reverse recovery time *	t _{rr}	$I_F = I_R = 10 \text{ mA}$ $I_{rr} = 1 \text{ mA}, R_L = 100 \Omega$		1.0		ns
Detection efficiency	η	$V_{IN} = 3 V_{(peak)}, f = 30 \text{ MHz}$ $R_L = 3.9 \text{ k}\Omega, C_L = 10 \text{ pF}$		65		%

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

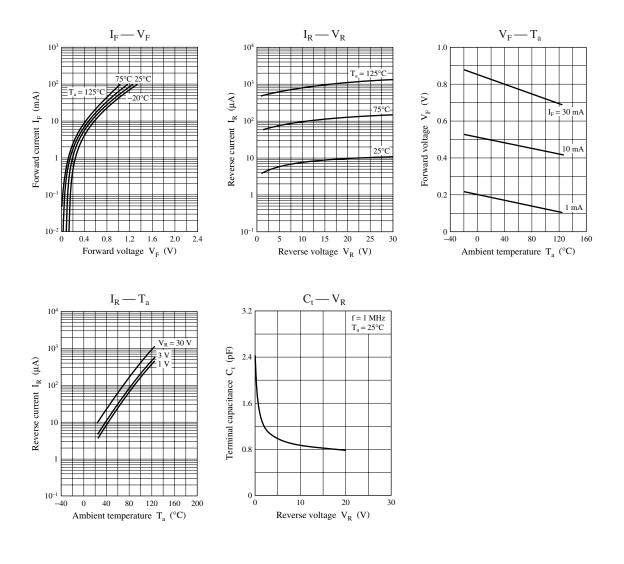
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.

- 3. Absolute frequency of input and output is 2 GHz.
- 4. *: t_{rr} measurement circuit



Note) The part number in the parenthesis shows conventional part number.



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